

2SC3512

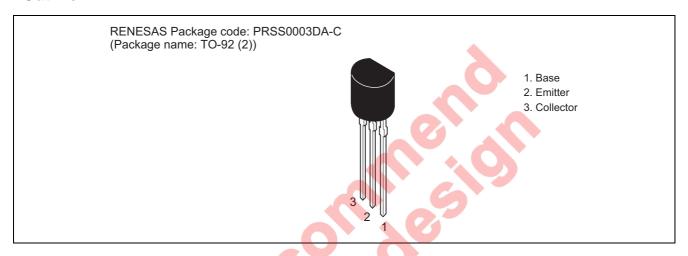
Silicon NPN Epitaxial

REJ03G0714-0300 Rev.3.00 Apr 20, 2006

Application

UHF / VHF wide band amplifier

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Collector to base voltage	V _{CBO}	15	V
Collector to emitter voltage	V _{CEO}	11	V
Emitter to base voltage	V_{EBO}	2	V
Collector current	Ic	50	mA
Collector power dissipation	Pc	600	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

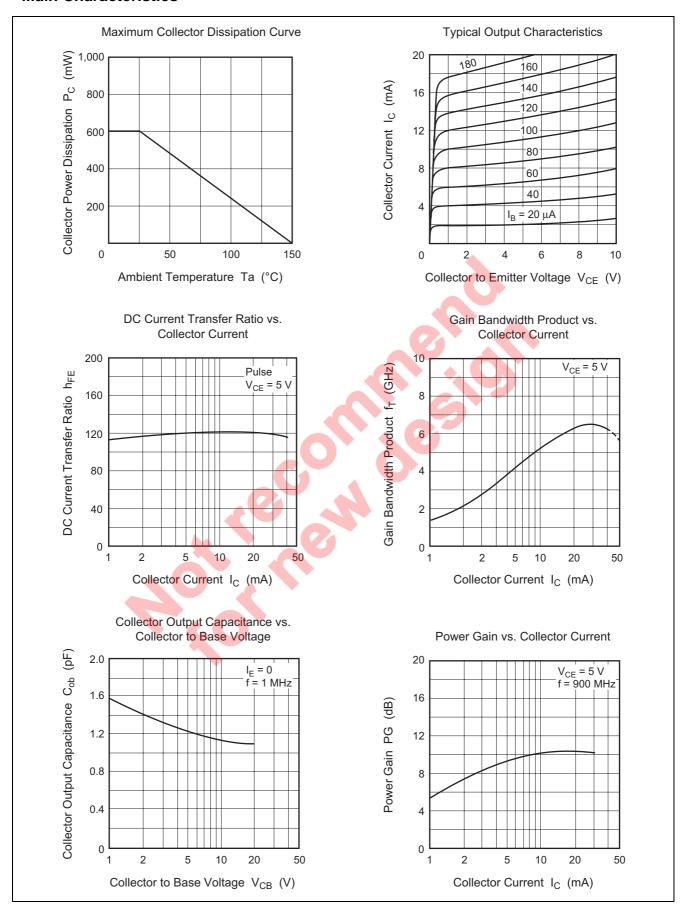
Electrical Characteristics

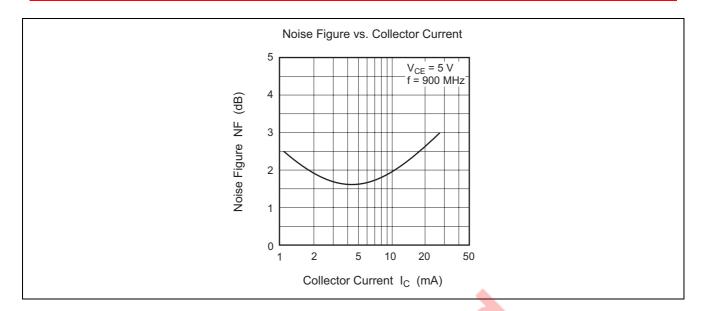
 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	V _{(BR)CBO}	15	_	_	V	$I_C = 10 \mu A, I_E = 0$
Collector to cutoff current	I _{CEO}	_	_	1	μΑ	V _{CE} = 10 V, R _{BE} = ∞
Emitter cutoff current	I _{EBO}	_	_	1	μΑ	$V_{EB} = 1 \text{ V}, I_{C} = 0$
Collector cutoff current	I _{CBO}	_	_	1	μΑ	$V_{CB} = 12 \text{ V}, I_{E} = 0$
DC current transfer ratio	h _{FE}	50	120	250		$V_{CE} = 5 \text{ V}, I_{C} = 20 \text{ mA}$
Collector output capacitance	Cob	_	1.2	1.6	pF	$V_{CB} = 5 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$
Gain bandwidth product	f⊤	_	6.0	_	GHz	$V_{CE} = 5 \text{ V}, I_{C} = 20 \text{ mA}$
Power gain	PG	_	10.5	_	dB	$V_{CE} = 5 \text{ V}, I_{C} = 20 \text{ mA},$
						f = 900 MHz
Noise figure	NF	_	1.6	_	dB	$V_{CE} = 5 \text{ V}, I_{C} = 5 \text{ mA},$
						f = 900 MHz



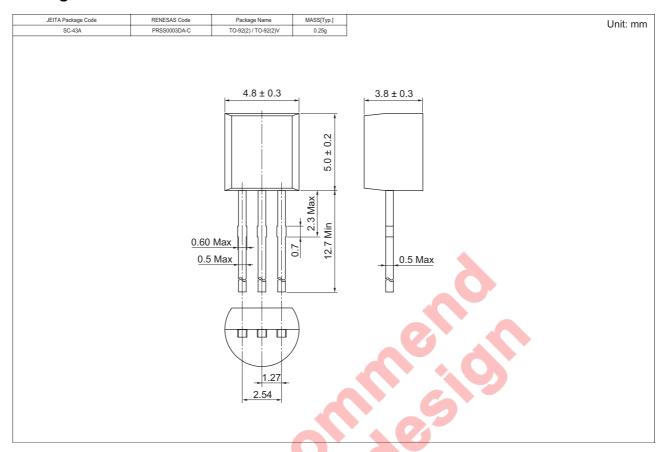
Main Characteristics







Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Containe	r
2SC3512TZ-E	2500	d Box, Radial Taping	

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